

# **Ion beam analysis of T and He in tritiated thin films**

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**With thanks to J. C. Banks, W.R. Wampler, B.L. Doyle,  
G. Bond, B. Vaandrager, K. Arstila, and P. Pusa.**

# Motivation: metal tritide films

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- ◆ **Metal tritide films are essential for applications such as neutron generators.**
  - **Problems:**
  - **T decays to  $^3\text{He}$ , forming bubbles and stressing the film.**
  - **O contamination influences hydriding efficiency and film stability.**
  
- ◆ **Tritide film composition and other properties are needed for understanding and controlling hydriding and aging problems.**
  
- ◆ **Several types of films are being studied:**
  - **$\text{ErT}_2$  films with 100% T, studied as the films age**
  - **$\text{ErD}_2$  films hydrided under various conditions**
  
- ◆ **Here we present:**
  - **Examples of high energy, heavy ion ERD profiling of  $^3\text{He}$ , T, D, H, O and C in these types of samples.**

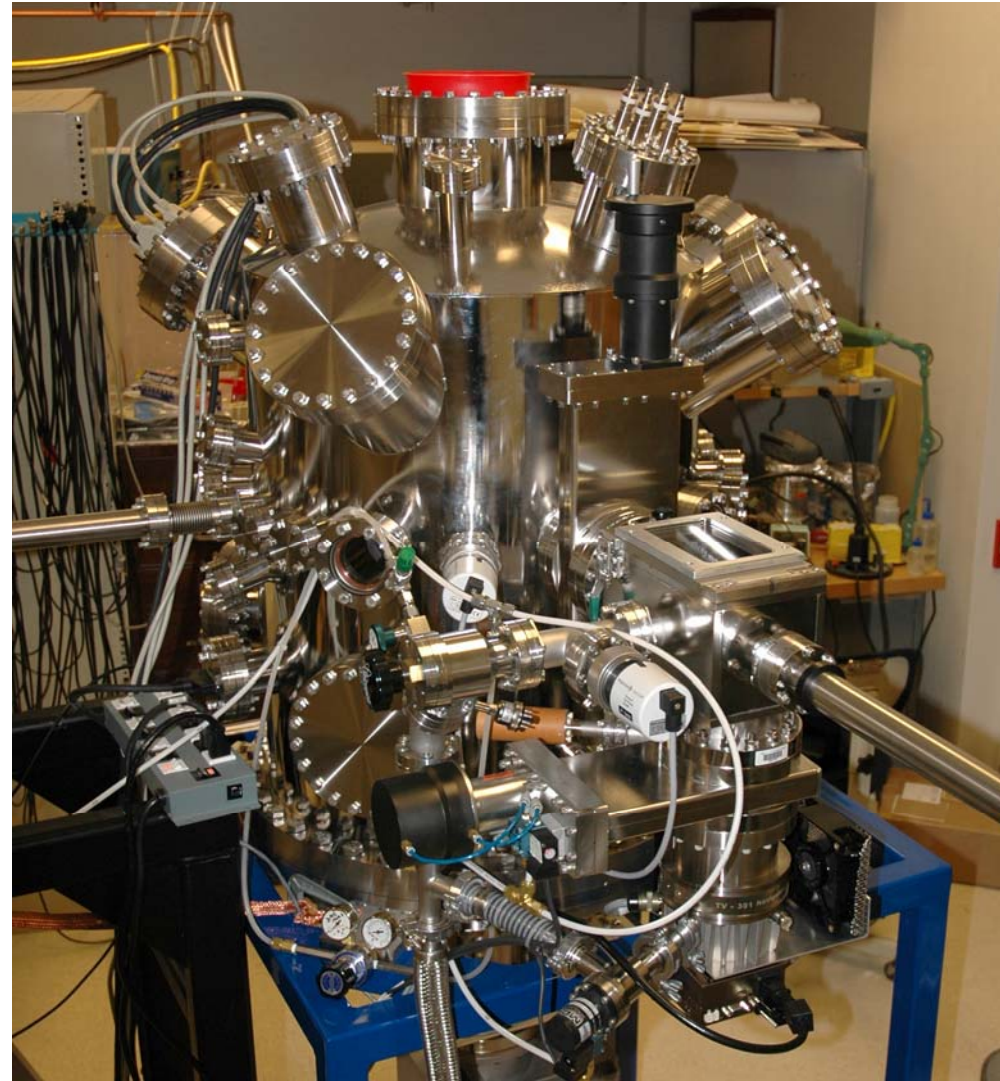
# High energy ERD system

## ◆ Problem:

- Need to analyze T,  $^3\text{He}$ , D, H, O, and C.
- Our existing ERD analysis chamber used for T could not measure  $^3\text{He}$  or O on Si.
- New system designed based on high energy, heavy ion beams and  $\Delta\text{E-E}$  detectors.

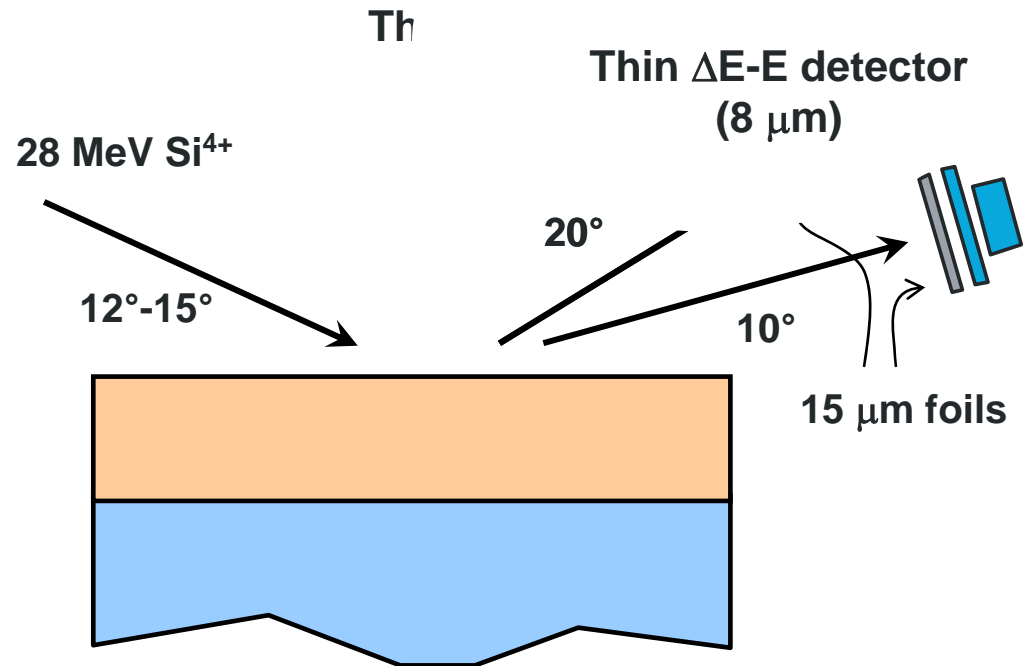
## ◆ Analysis chamber:

- beam line on 7 MV Tandem
- 6-axis custom goniometer
- all-metal ion-pumped chamber
- load lock with heating stage



# Analysis method

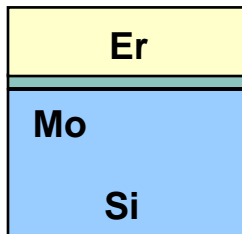
- Heavy ion elastic recoil detection (ERD) with 28 MeV  $\text{Si}^{4+}$  analysis beam incident at  $12^\circ$ - $15^\circ$
- Thick  $\Delta E$ -E detector to profile H, D, T,  $^3\text{He}$
- Thin  $\Delta E$ -E detector to profile O, C
- Each detector pair has a  $15\ \mu\text{m}$  foil to block the Si analysis beam and curved slits to optimize resolution.



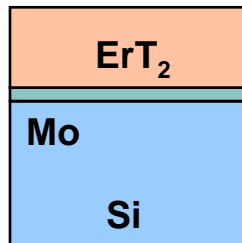
# Example: ErT<sub>2</sub> layers on Mo/Si

## Sample preparation

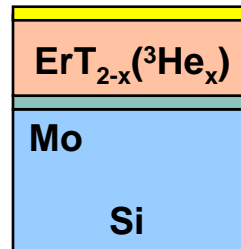
500 nm Er  
95 nm Mo  
Silicon



Hydrided  
with 100%  
T at LANL



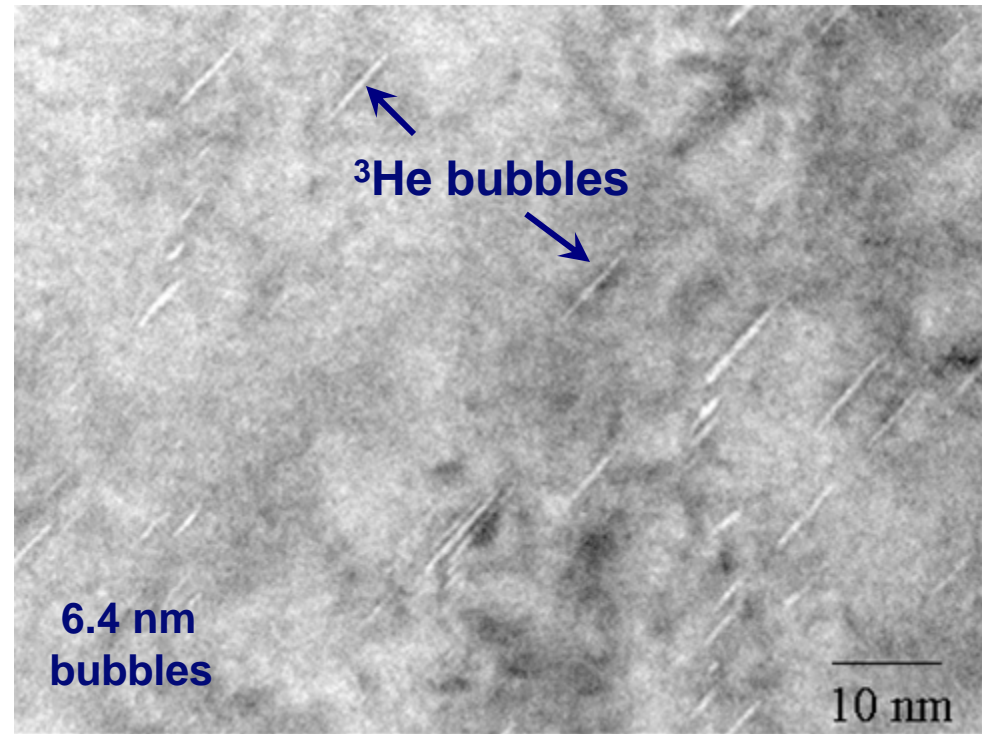
Aged in  
vacuum



Oxide forms during hydriding and upon air exposure.

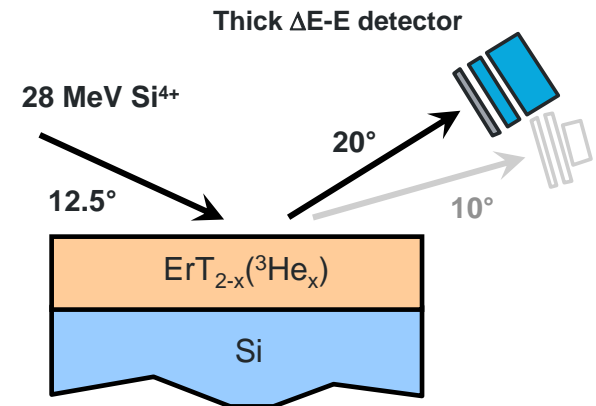
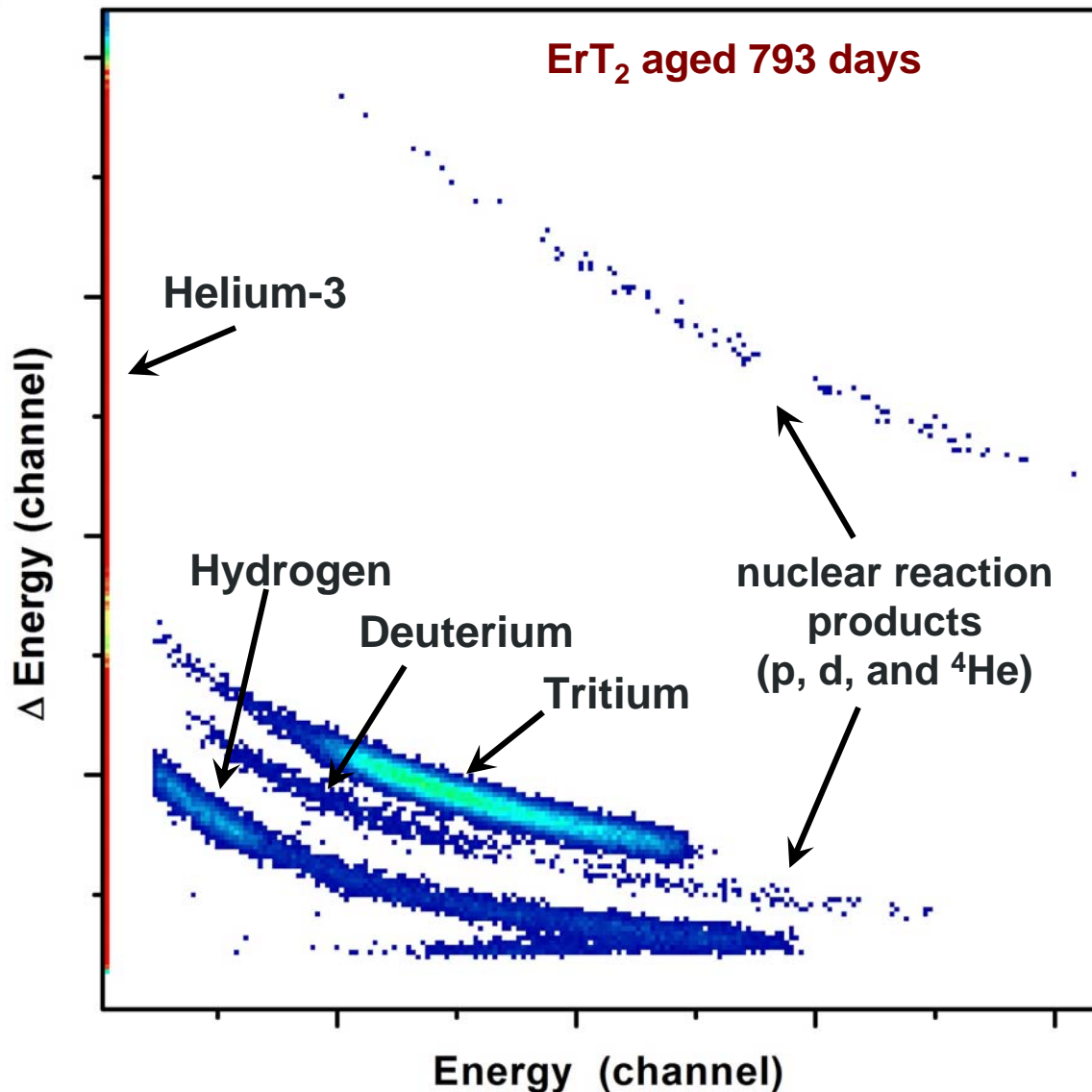
Tritium decays into <sup>3</sup>He, forming platelet-like bubbles on (111) planes.

TEM cross-section  
bright-field, ~{110} zone  
62 days after hydriding.



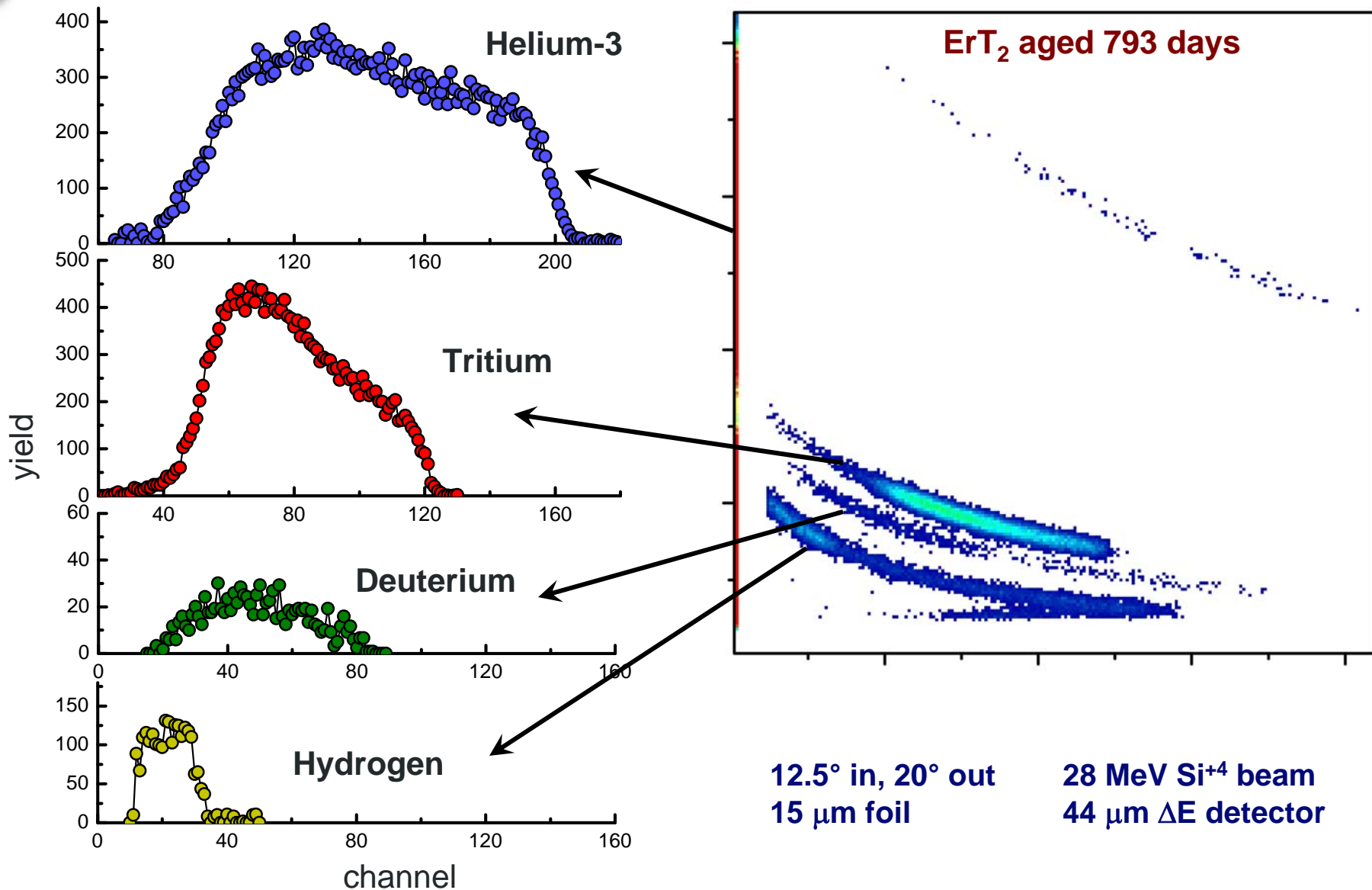
TEM with Gillian Bond, New Mexico Institute of Mining and Technology

# Coincidence map for **thick** $\Delta E$ -E detector

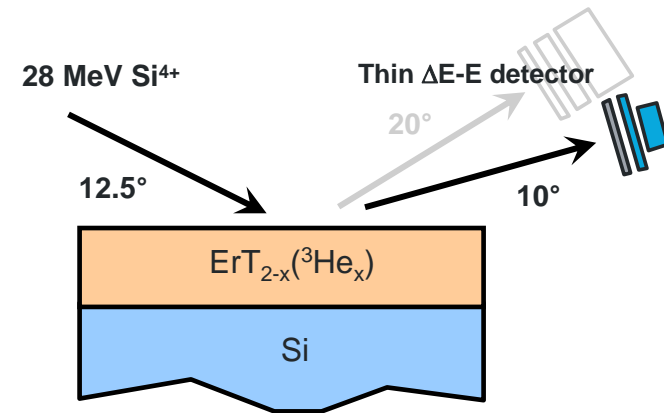
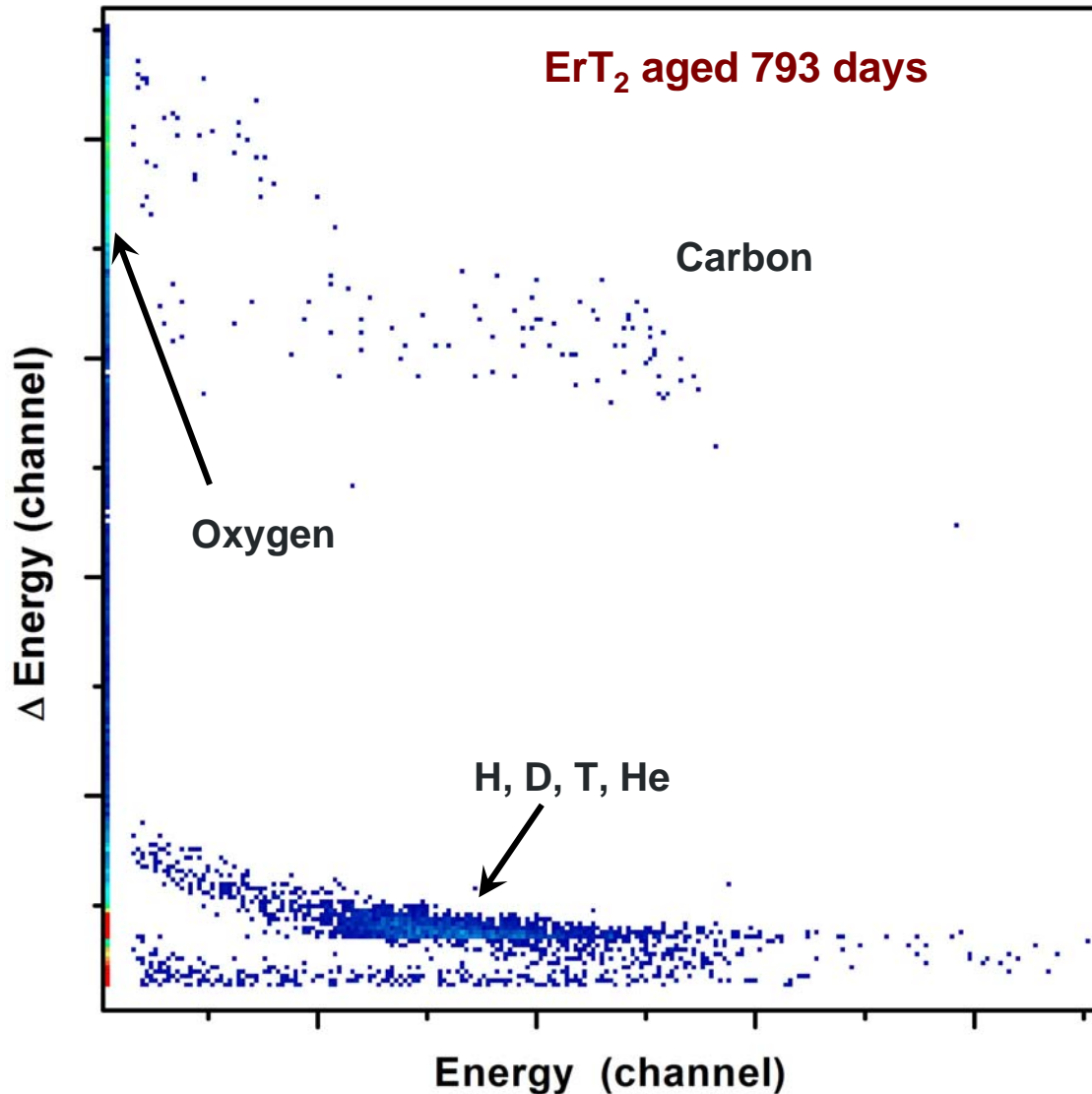


12.5° in, 20° out  
28 MeV Si<sup>4+</sup> beam  
15  $\mu$ m foil  
44  $\mu$ m  $\Delta E$  detector

# Spectra for **thick** $\Delta E$ -E detector



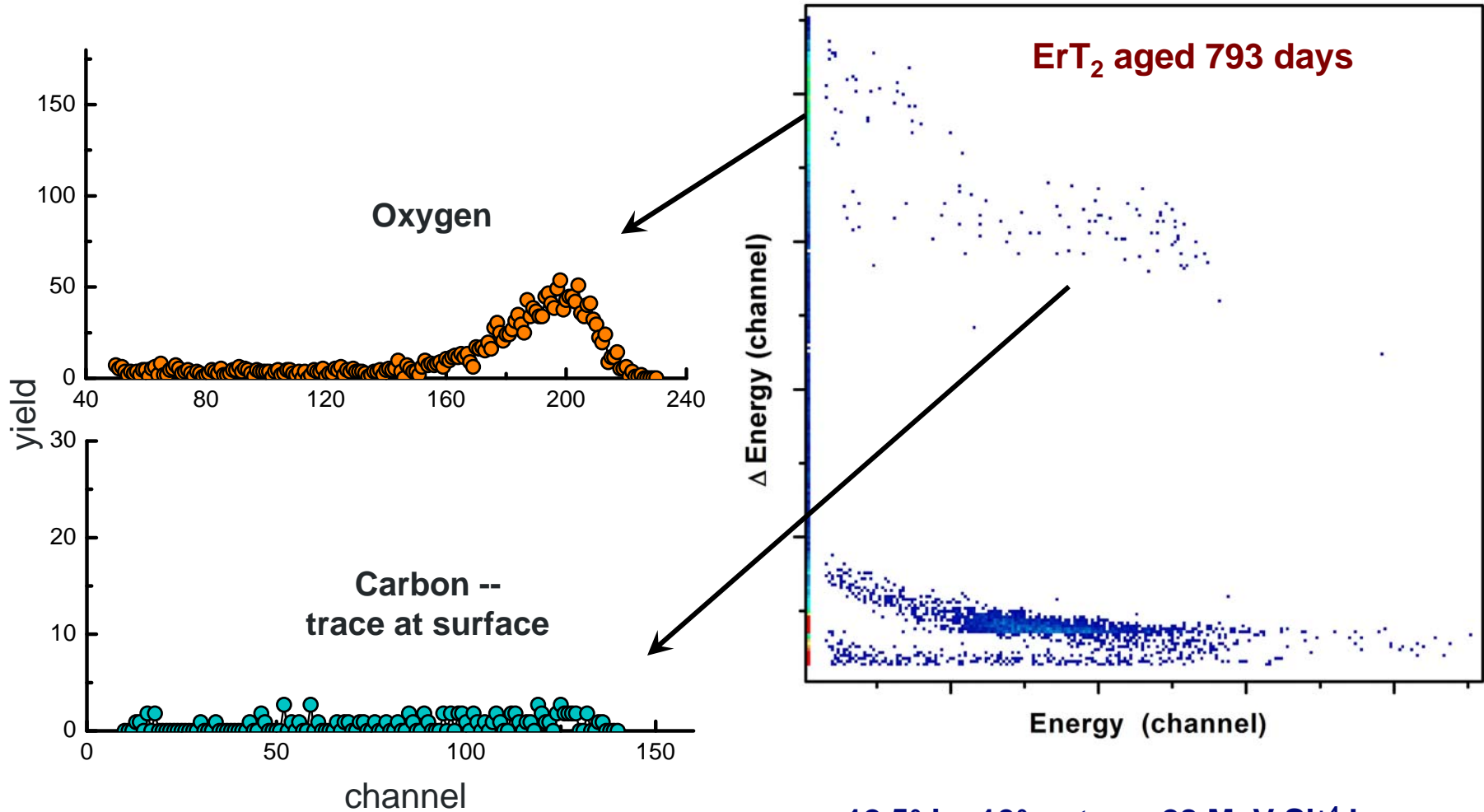
# Coincidence map for **thin** $\Delta E$ -E detector



12.5° in, 10° out  
28 MeV Si<sup>4+</sup> beam  
15  $\mu$ m foil  
8  $\mu$ m  $\Delta E$  detector



# Spectra for **thin** $\Delta E$ -E detector



12.5° in, 10° out  
15  $\mu$ m foil

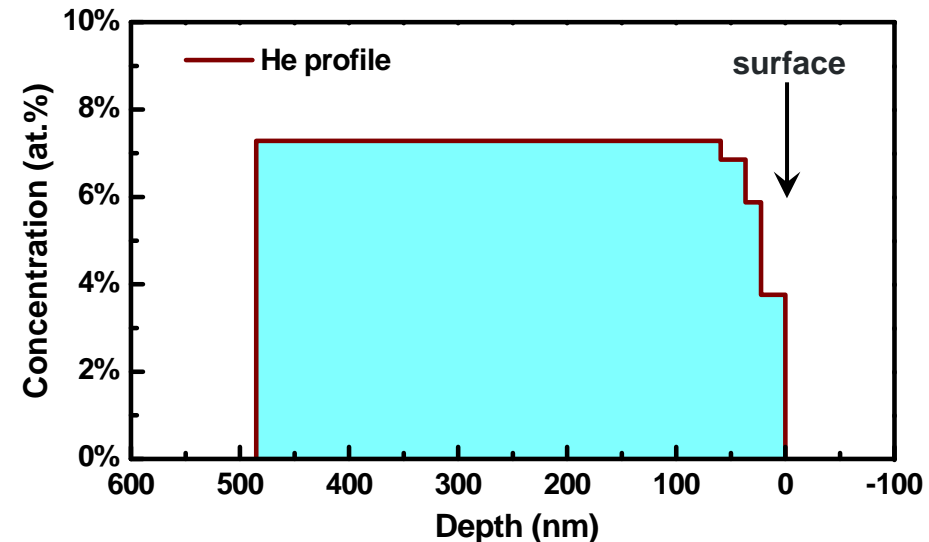
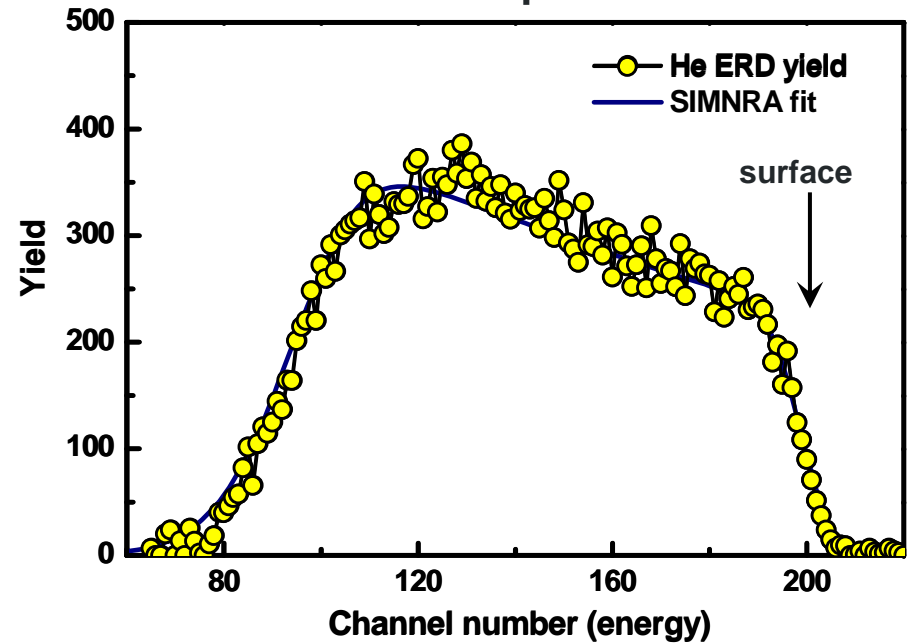
28 MeV Si<sup>4+</sup> beam  
8  $\mu$ m  $\Delta E$  detector

# Analysis using SIMNRA

- Direct conversion of ERD data to a depth profile is generally not possible.
- Instead, the data must be analyzed by fitting with an ion beam interaction code such as SIMNRA\*.
- A test profile including all elements is input, along with energies, angles, etc.
- Ion interaction cross-sections, stopping powers, straggling and geometrical broadening are all calculated by the simulation.
- **The concentration profile is varied until a best fit is obtained.**

\*SIMNRA vs. 6.03, Dr. Matej Mayer, Max Planck Inst.

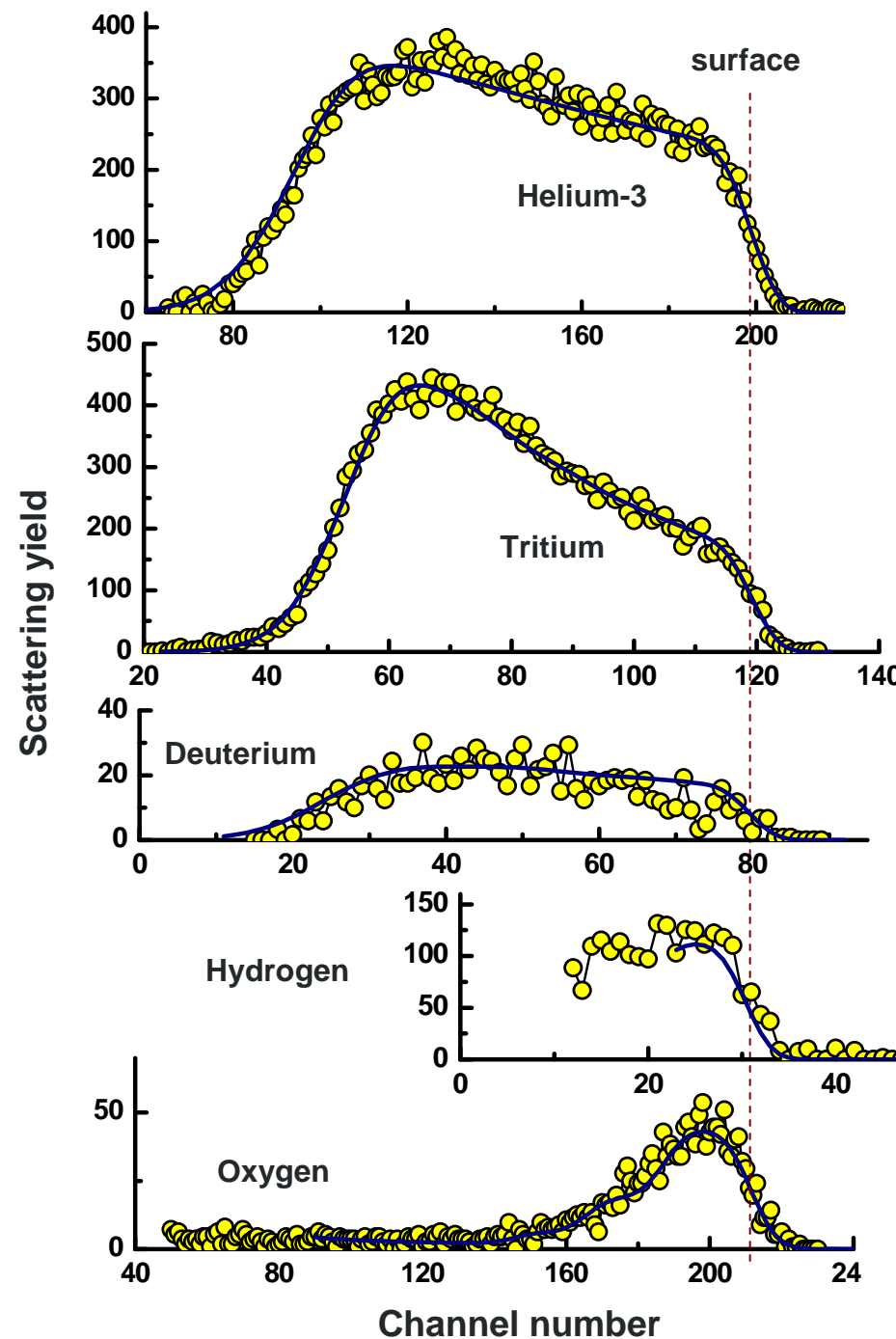
### Helium-3 spectrum



# Analysis using SIMNRA

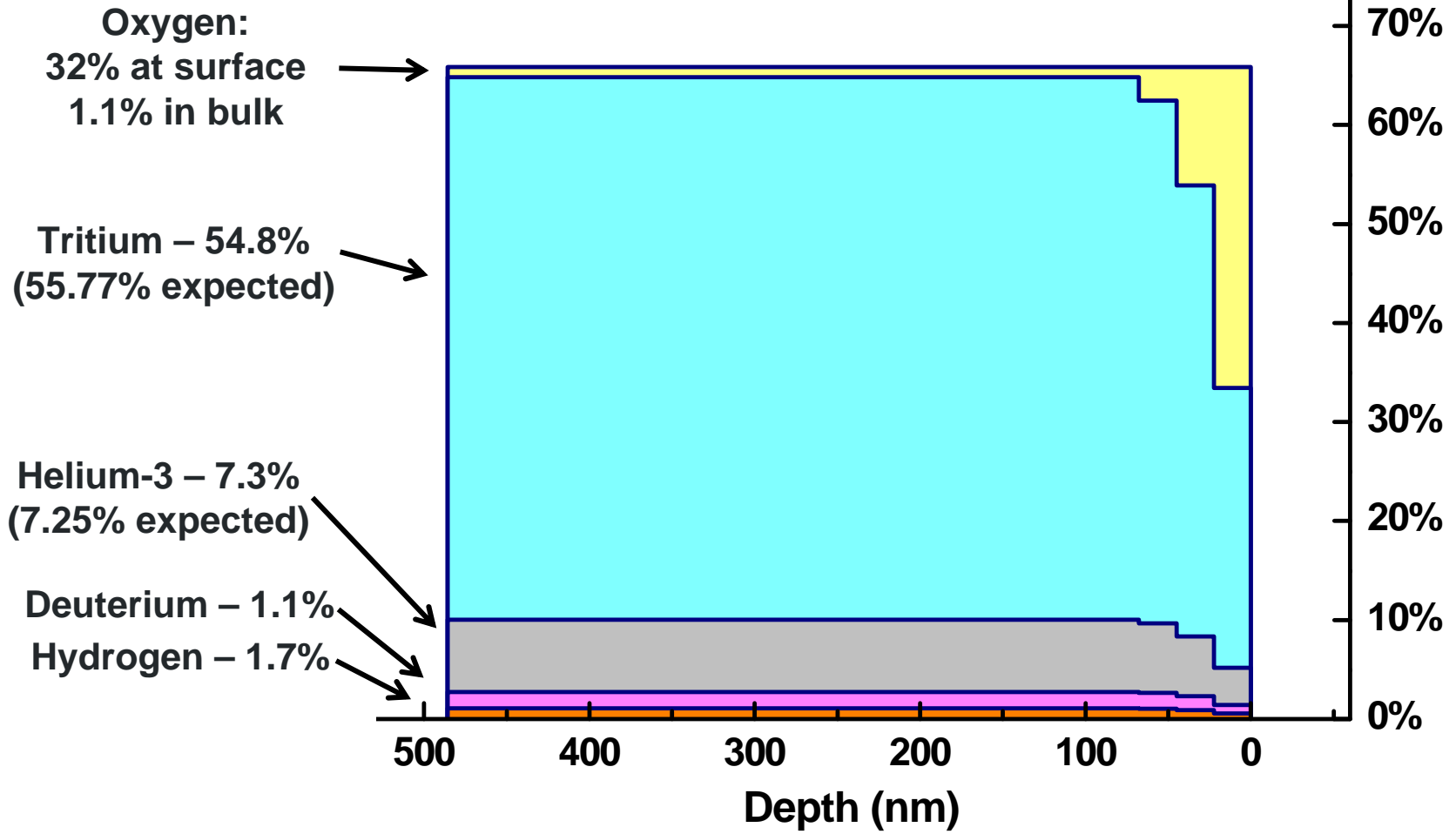
**SIMNRA fits of the elemental spectra from the ErT<sub>2</sub> sample aged 793 days**

- Broadening is due to both straggling and sample roughness.
- T cross-section is non-Rutherford and had to be deduced by fitting T spectra obtained at 24–30 MeV, using a sample calibrated at lower energy.
- Energy and hence depth resolution vary with element – the best depth resolution is for O.



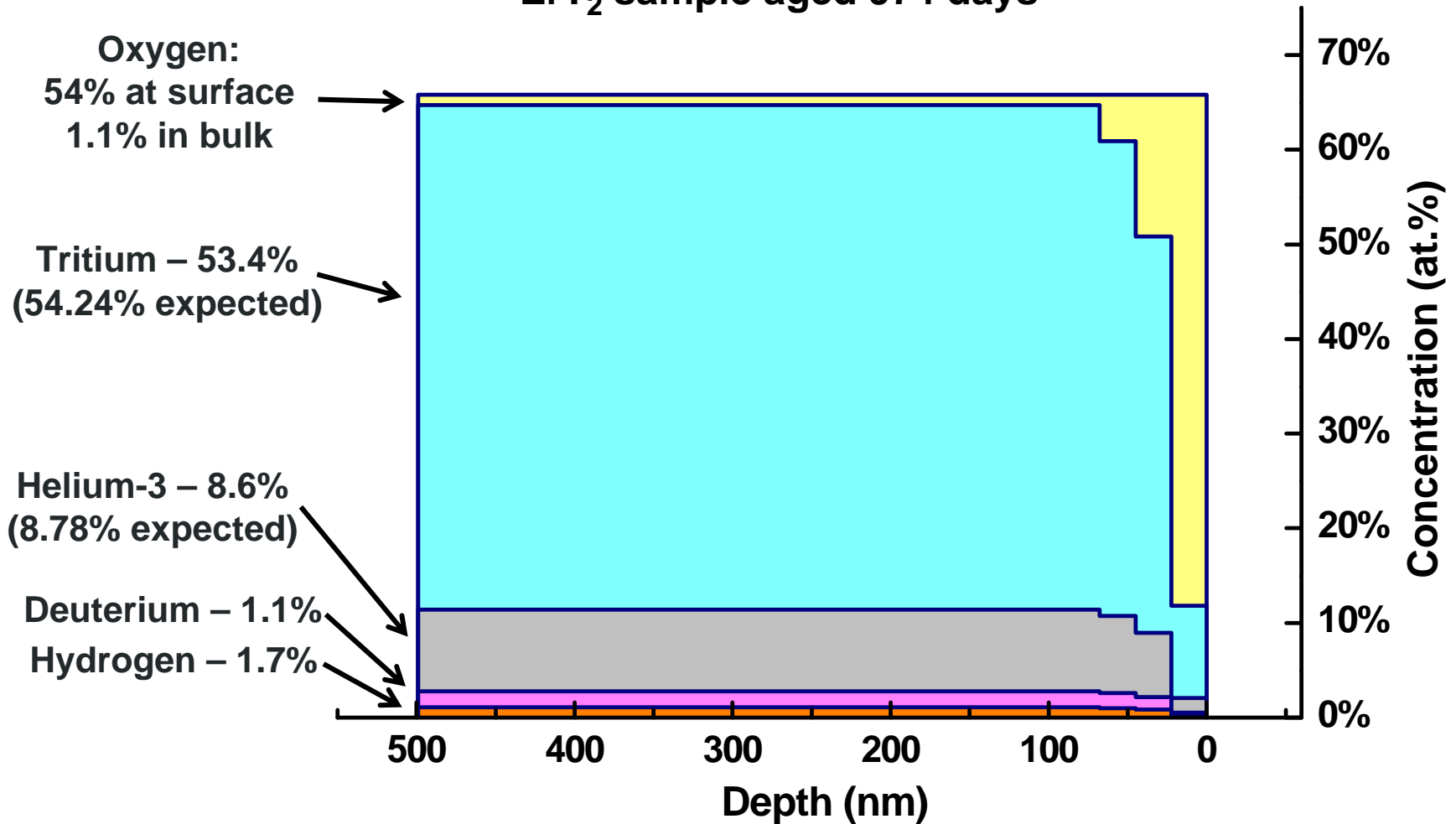
# Concentration profiles using SIMNRA

ErT<sub>2</sub> sample aged 793 days



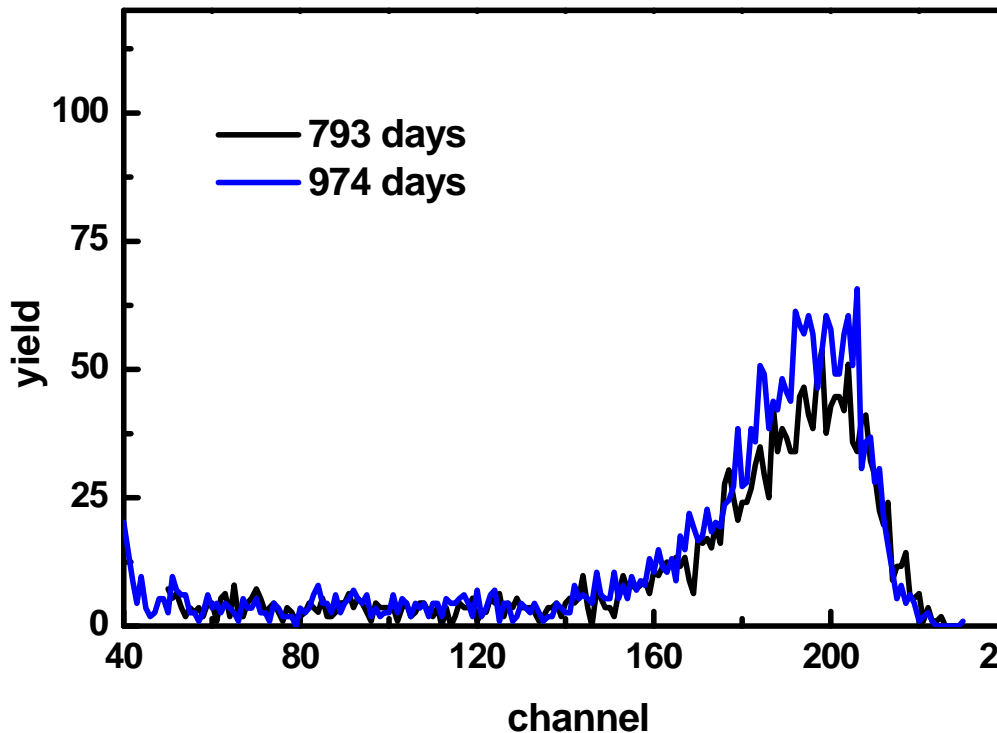
# Concentration profiles using SIMNRA

ErT<sub>2</sub> sample aged 974 days

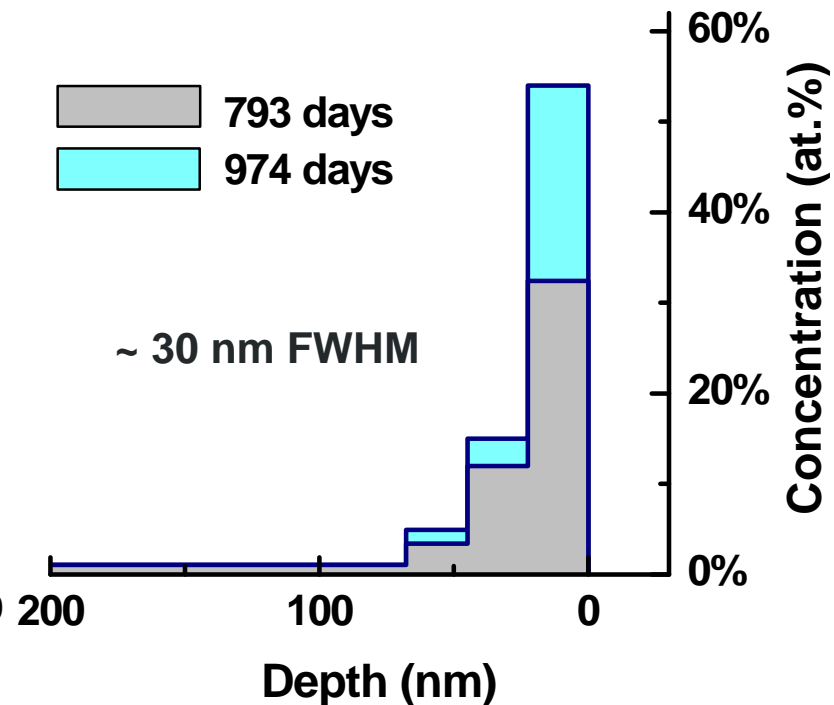


# Oxide growth with aging

Normalized ERD Oxygen spectra  
(same  $\text{ErT}_2$  sample)



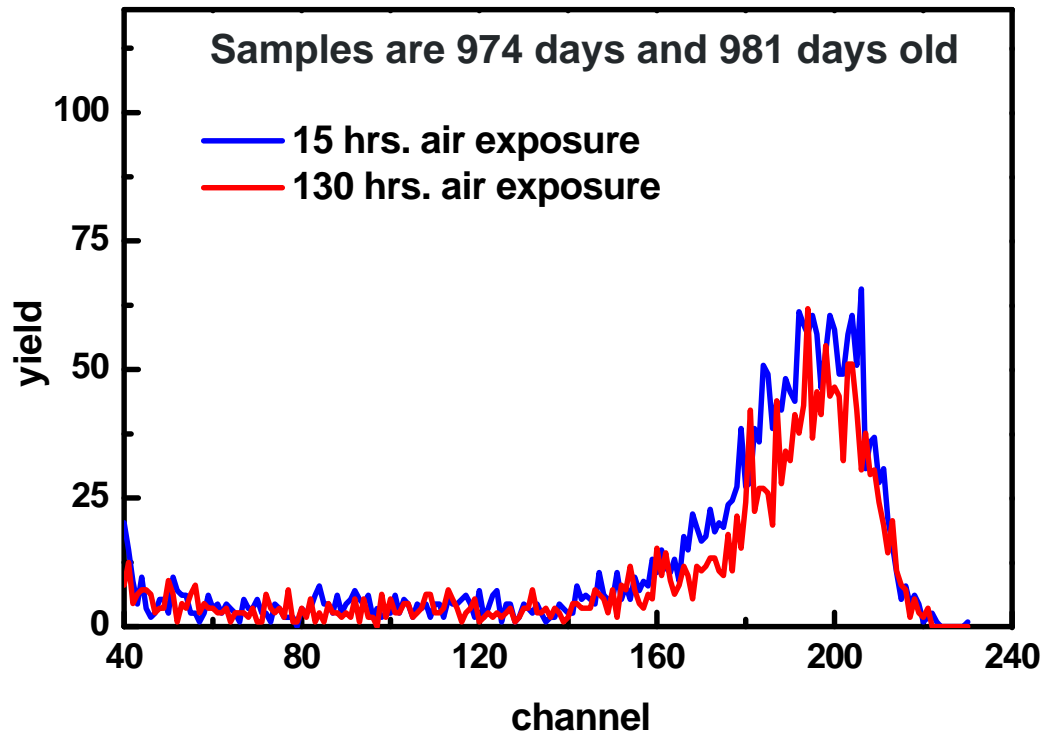
SIMNRA Oxygen profiles



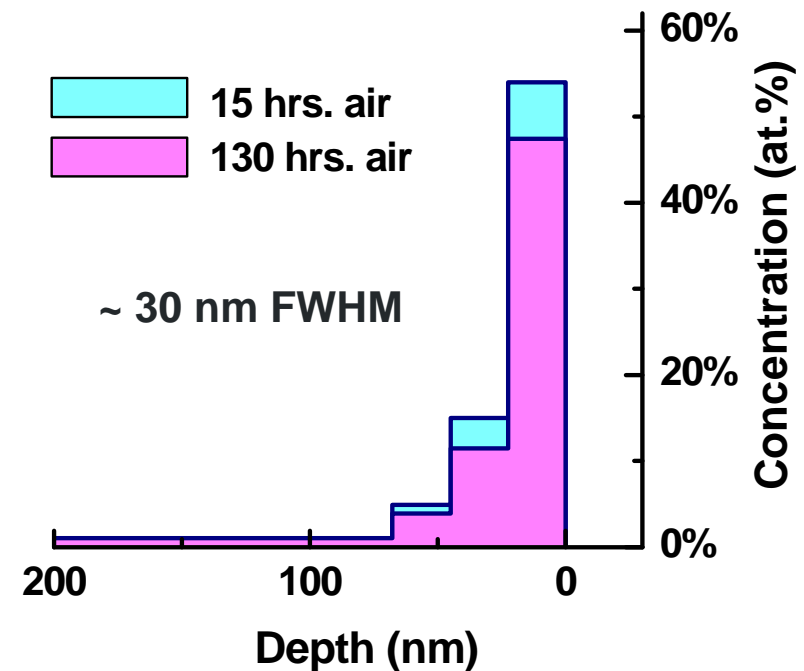
The oxide on this  $\text{ErT}_2$  sample is growing slowly as it ages.  
Spectral broadening masks the effect somewhat in the raw data.

# Oxide growth with air exposure

Normalized ERD Oxygen spectra  
(same age  $\text{ErT}_2$  samples)



SIMNRA Oxygen profiles

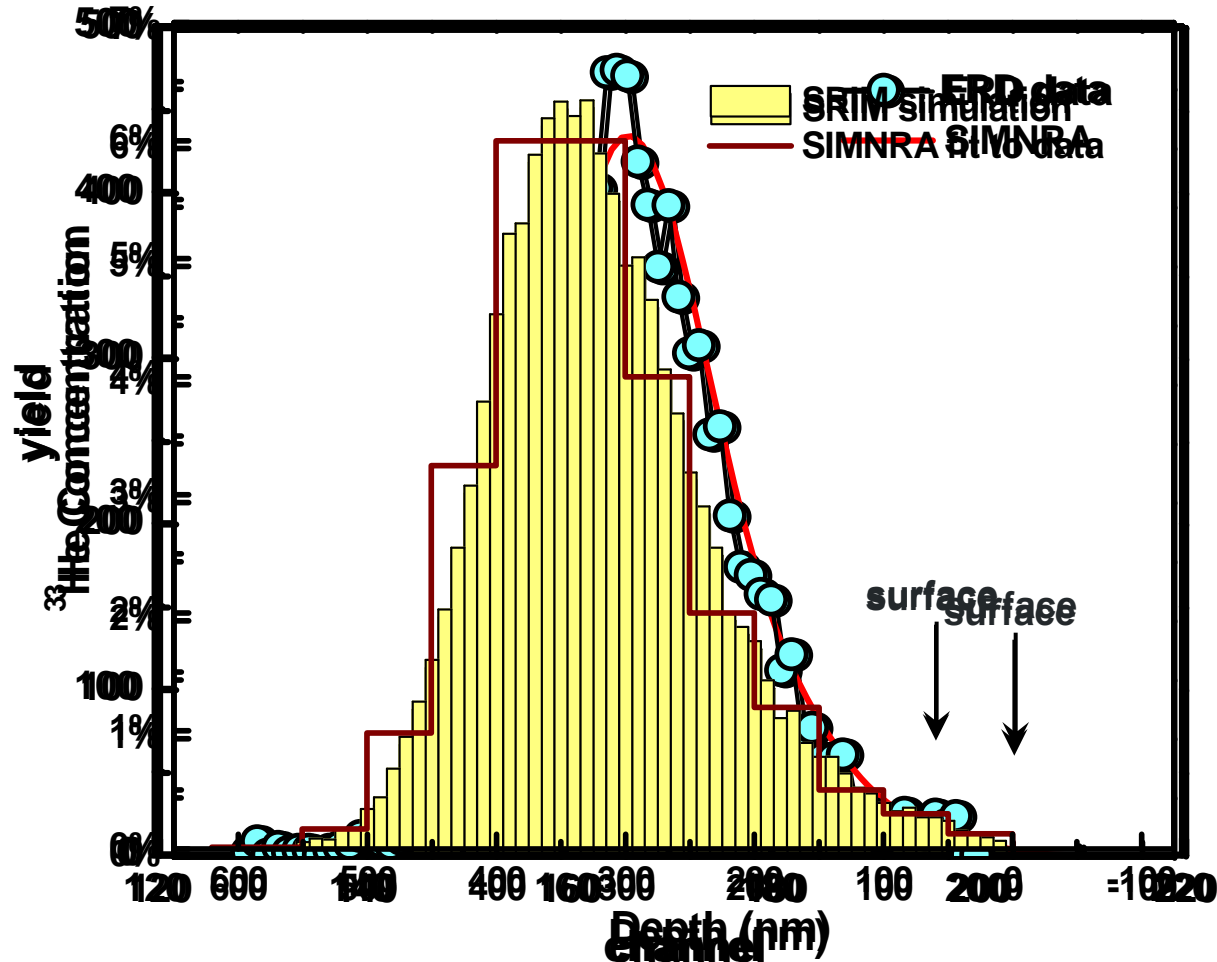


The oxides on these parallel  $\text{ErT}_2$  samples are nearly identical, even though the 2<sup>nd</sup> sample has been out of vacuum nearly 10X as much.

 Oxide growth may be controlled by the T activity.

## Example: $^3\text{He}$ -implanted Si

$1.6 \times 10^{16}$   $^3\text{He}/\text{cm}^2$  implanted at 40 keV into Si.



- Single energy implant, resulting in a peak 6 at.%  $^3\text{He}$  at 350 nm.
- Depth distribution calculated using the SRIM 2003 Monte Carlo code.
- 28 MeV ERD spectrum has the same general shape.
- SIMNRA fitting with a multi-layer profile matches the experiment.
- The SIMNRA profile is very close to the SRIM distribution.



# Summary

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A new ERD ion beam analysis system allows non-destructive profiling of  $^3\text{He}$ , T, H, D, O, and C with down to 10 nm resolution.

## Issues:

- very sensitive to sample thickness and mounting angles.
- cross-sections and stopping powers can be uncertain at these energies and for these elements (T,  $^3\text{He}$ , D).
- nuclear reaction products can interfere.
- sample roughness limits depth resolution.
- most problems solved by use of standard samples.